TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCT240AF,TC74VHCT240AFT,TC74VHCT240AFK TC74VHCT244AF,TC74VHCT244AFT,TC74VHCT244AFK

Octal Bus Buffer

TC74VHCT240AF/AFT/AFK Inverted, 3-State Outputs

TC74VHCT244AF/AFT/AFK Non-Inverted, 3-State Outputs

The TC74VHCT240A and 244A are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C²MOS technology. They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74VHCT240A is an inverting 3-state buffer having two active-low output enables. The TC74VHCT244A is a non-inverting 3-state buffer, and has two active-low output

These devices are designed to be used with 3-state memory address drivers, etc.

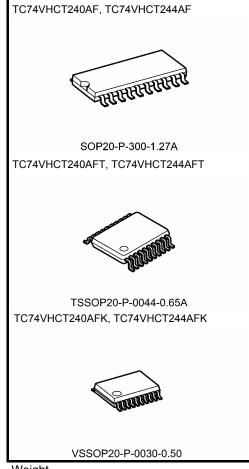
The input voltage are compatible with TTL output voltage. These devices may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

Features

- High speed: $t_{pd} = 6.1 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs: VIL = 0.8 V (max) VIH = 2.0 V (min)
- · Power down protection is provided on all inputs and outputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: VOLP = 1.0 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 240/244 type.

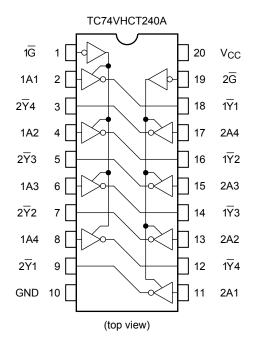


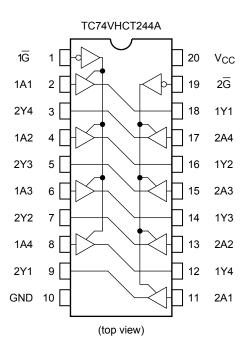
Weight

SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

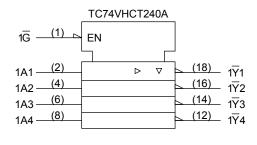


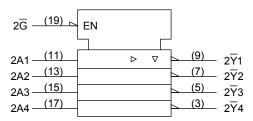
Pin Assignment

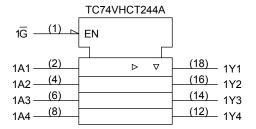


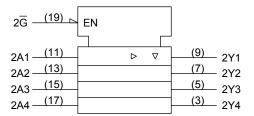


IEC Logic Symbol









Truth Table

Inp	uts	Outputs				
G	An	Yn	\overline{Y}_n			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

X: Don't care

Z: High impedance

Yn: TC74VHCT244A \overline{Y}_n : TC74VHCT240A

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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	\/a=	-0.5 to 7.0 (Note 2)	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	ΙιΚ	-20	mA
Output diode current	lok	±20 (Note 4)	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V	0 to 5.5 (Note 2)	V
Output voltage	Vout	0 to V _{CC} (Note 3)	V
Operating temperature	T _{opr}	–40 to 85	°C
Input rise and fall time	dt/dV	0 to 20	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

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Note 2: Output in off-state

Note 3: High or low state



Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
	5,25.		V _{CC} (V)	Min	Тур.	Max	Min	Max		
High-level input voltage	V _{IH}	_		4.5 to 5.5	2.0	_	_	2.0	_	V
Low-level input voltage	V_{IL}	_		4.5 to 5.5		_	0.8	_	0.8	V
High-level output	V	V _{IN}	$I_{OH} = -50 \mu A$	4.5	4.40	4.50	_	4.40	_	V
voltage	$=$ V _{IH} or V _{IL} $I_{OH} = -8 \text{ mA}$		4.5	3.94	_	_	3.80	_	V	
Low-level output voltage V _{OL}	V	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	4.5	_	0.0	0.10	_	0.10	V
			I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		5.5	_	_	±0.25	_	±2.50	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μА
	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	_	40.0	μА
Quiescent supply current	Ісст	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	_	1.50	mA
Output leakage current	I _{OPD}	V _{OUT} = 5.5 V		0	_	_	0.5	_	5.0	μА

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AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics Symbo		Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
	,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
Propagation delay time	t _{pLH}	_	5.0 ± 0.5	15		5.6	7.8	1.0	9.0	ns
(TC74VHCT240A)	t_{pHL}		0.0 = 0.0	50	_	6.1	8.8	1.0	10.0	110
Propagation delay time	t _{pLH}	_	— 5.0 ± 0.5	15	_	5.4	7.4	1.0	8.5	ns
(TC74VHCT244A)	t_{pHL}			50	_	5.9	8.4	1.0	9.5	110
3-state output enable tpZL time tpZH	$R_{l} = 1 k\Omega$	5.0 ± 0.5	15	_	7.7	10.4	1.0	12.0	ns	
	t _{pZH}		0.0 ± 0.0	50	_	8.2	11.4	1.0	13.0	113
3-state output disable time	t _{pLZ} t _{pHZ}	$R_L = 1 \text{ k}\Omega$	5.0 ± 0.5	50	_	8.8	11.4	1.0	13.0	ns
Output to output skew	t _{osLH}	(Note 1)	5.0 ± 0.5	50	_	_	1.0	_	1.0	ns
Input capacitance	C _{IN}	_			_	4	10	_	10	pF
Output capacitance	C _{OUT}	_			_	9	_	_	_	pF
Power dissipation capacitance (Note 2)		TC74VHCT240A		_	19	_	_	_	pF	
	C _{PD}	TC74VHCT244A			_	18	_	_	_	ρı

Note 1: Parameter guaranteed by design.

$$t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \ t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

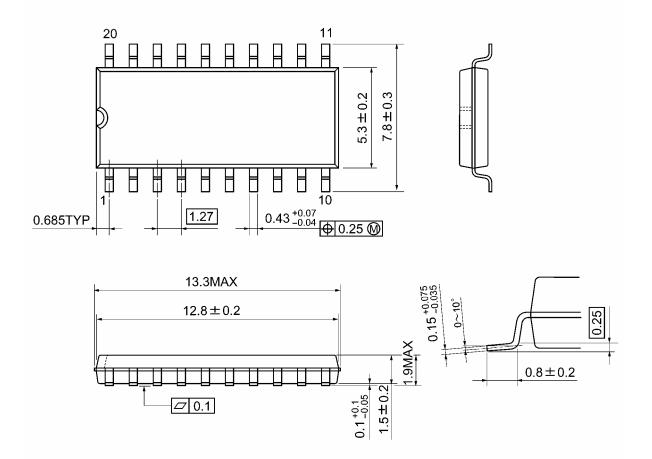
Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
			V _{CC} (V)	Тур.	Limit	Oill
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V _{OL}	V_{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	V
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0		2.0	٧
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	0.8	V



Package Dimensions

SOP20-P-300-1.27A Unit: mm



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Weight: 0.22 g (typ.)

0.45~0.75



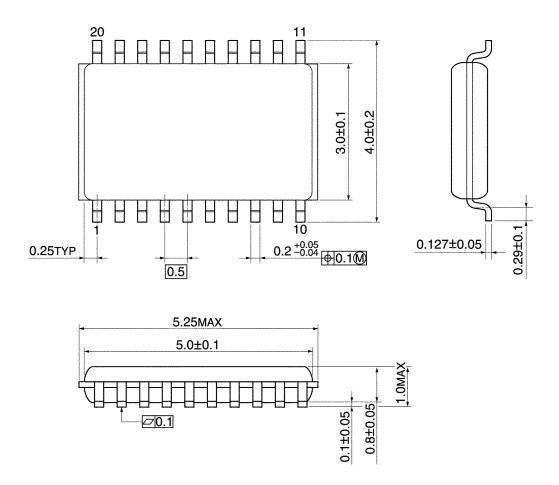
Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm 6.4 ± 0.2 $0.22\substack{+0.09 \\ -0.06}$ 0.65 0.325TYP | |0.13M 6.9MAX 6.5±0.1 1.2MAX 0~10 1.0±0.05 0.1±0.05 S **∅**0.1|S (0.5)

Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



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Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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